# Automotive P-Channel 60 V (D-S) 175 °C MOSFET

PRODUCT SUMMARY	
V <sub>DS</sub> (V)	-60
$R_{DS(on)}(\Omega)$ at $V_{GS} = -10 \text{ V}$	0.018
$R_{DS(on)}(\Omega)$ at $V_{GS} = -4.5 \text{ V}$	0.024
I <sub>D</sub> (A)	-52
Configuration	Single
Package	PowerPAK SO-8L

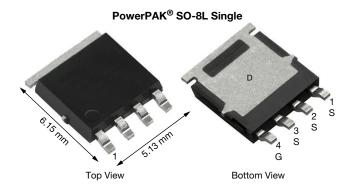
#### **FEATURES**

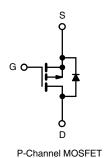
- TrenchFET® power MOSFET
- 100 % R<sub>g</sub> and UIS tested
- AEC-Q101 qualified <sup>c</sup>
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912





ROHS COMPLIANT HALOGEN FREE





ABSOLUE MAXIMUM RATINGS (T	<sub>C</sub> = 25 °C, unless	otherwise noted)			
PARAMETER		SYMBOL	LIMIT	UNIT	
Drain-Source Voltage		$V_{DS}$	-60	V	
Gate-Source Voltage		$V_{GS}$	± 20	V	
Continuous Drain Current	T <sub>C</sub> = 25 °C	1	-52		
Continuous Drain Current	T <sub>C</sub> = 125 °C	Ι <sub>D</sub>	-30		
Continuous Source Current (Diode Conduction)	)	I <sub>S</sub>	-75	Α	
Pulsed Drain Current <sup>a</sup>		I <sub>DM</sub>	-200		
Single Pulse Avalanche Current	L = 0.1 mH	I <sub>AS</sub>	-40	V	
Single Pulse Avalanche Energy	L=0.11IIII	E <sub>AS</sub>	80	mJ	
Maximum Power Dissipation <sup>a</sup>	T <sub>C</sub> = 25 °C	P <sub>D</sub>	83	W	
	T <sub>C</sub> = 125 °C	r <sub>D</sub>	27		
Operating Junction and Storage Temperature F	Range	T <sub>J</sub> , T <sub>stg</sub>	-55 to +175	°C	
Soldering Recommendations (Peak Temperature) d, e			260	C	

THERMAL RESISTANCE RATINGS				
PARAMETER		SYMBOL	LIMIT	UNIT
Junction-to-Ambient	PCB Mount b	$R_{thJA}$	65	°C/W
Junction-to-Case (Drain)		$R_{thJC}$	1.8	C/VV

#### Notes

- a. Pulse test; pulse width  $\leq$  300  $\mu$ s, duty cycle  $\leq$  2 %.
- b. When mounted on 1" square PCB (FR4 material).
- c. Parametric verification ongoing.
- d. See solder profile (<a href="https://www.vishay.com/doc?73257">www.vishay.com/doc?73257</a>). The PowerPAK SO-8L is a leadless package. The end of the lead terminal is exposed copper (not plated) as a result of the singulation process in manufacturing. A solder fillet at the exposed copper tip cannot be guaranteed and is not required to ensure adequate bottom side solder interconnection.
- e. Rework conditions: manual soldering with a soldering iron is not recommended for leadless components.



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PARAMETER	SYMBOL	TES	TEST CONDITIONS		TYP.	MAX.	UNIT
Static							
Drain-Source Breakdown Voltage	V <sub>DS</sub>	V <sub>GS</sub>	= 0, I <sub>D</sub> = -250 μA	-60	-	-	V
Gate-Source Threshold Voltage	V <sub>GS(th)</sub>	V <sub>DS</sub> =	V <sub>GS</sub> , I <sub>D</sub> = -250 μA	-1.5	-2.0	-2.5	V
Gate-Source Leakage	I <sub>GSS</sub>	V <sub>DS</sub> =	0 V, V <sub>GS</sub> = ± 20 V	=	-	± 100	nA
		$V_{GS} = 0 V$	V <sub>DS</sub> = -60 V	-	-	-1	
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	$V_{GS} = 0 V$	V <sub>DS</sub> = -60 V, T <sub>J</sub> = 125 °C	-	-	-50	μΑ
		$V_{GS} = 0 V$	V <sub>DS</sub> = -60 V, T <sub>J</sub> = 175 °C	-	-	-150	•
On-State Drain Current <sup>a</sup>	I <sub>D(on)</sub>	V <sub>GS</sub> = -10 V	$V_{DS} \le -5 V$	-30	-	-	Α
		V <sub>GS</sub> = -10 V	I <sub>D</sub> = -3.5 A	-	0.0155	0.0180	
Drain-Source On-State Resistance a	В	V <sub>GS</sub> = -4.5 V	I <sub>D</sub> = -3.1 A	-	0.0206	0.0240	Ω
Drain-Source On-State nesistance *	R <sub>DS(on)</sub>	V <sub>GS</sub> = -10 V	I <sub>D</sub> = -3.5 A, T <sub>J</sub> = 125 °C	-	0.0255	-	52
		V <sub>GS</sub> = -10 V	I <sub>D</sub> = -3.5 A, T <sub>J</sub> = 175 °C	=	0.0310	-	
Forward Transconductance b	9 <sub>fs</sub>	V <sub>DS</sub> =	-30 V, I <sub>D</sub> = -15 A	=	40	-	S
Dynamic <sup>b</sup>							
Input Capacitance	C <sub>iss</sub>			-	3448	4586	
Output Capacitance	C <sub>oss</sub>	$V_{GS} = 0 V$	V <sub>DS</sub> = -30 V, f = 1 MHz	=	374	497	рF
Reverse Transfer Capacitance	C <sub>rss</sub>			-	234	312	
Total Gate Charge <sup>c</sup>	Qg			=	73	108	
Gate-Source Charge <sup>c</sup>	Q <sub>gs</sub>	V <sub>GS</sub> = -10 V	$V_{DS} = -40 \text{ V}, I_{D} = -15 \text{ A}$	=	10	-	nC
Gate-Drain Charge <sup>c</sup>	Q <sub>gd</sub>			=	20	-	
Gate Resistance	Rg		f = 1 MHz	0.5	1.1	2	Ω
Turn-On Delay Time <sup>c</sup>	t <sub>d(on)</sub>			-	12	17	
Rise Time <sup>c</sup>	t <sub>r</sub>	V <sub>DD</sub> =	: -30 V, $R_L = 30 \Omega$	-	19	26	
Turn-Off Delay Time <sup>c</sup>	t <sub>d(off)</sub>	I <sub>D</sub> ≅ -1 A, \	$V_{\rm GEN}$ = -10 V, $R_{\rm g}$ = 6 $\Omega$	-	88	117	ns
Fall Time <sup>c</sup>	t <sub>f</sub>			ı	45	60	
Source-Drain Diode Ratings and Chara	cteristics <sup>b</sup>						
Pulsed Current <sup>a</sup>	I <sub>SM</sub>			-	-	-200	Α
Forward Voltage	V <sub>SD</sub>	I	-2.5 A, V <sub>GS</sub> = 0	_	-0.8	-1.2	V

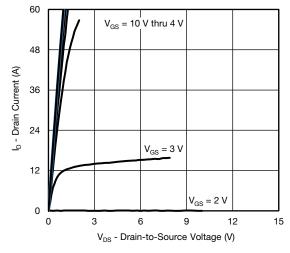
## **Notes**

- a. Pulse test; pulse width  $\leq$  300 µs, duty cycle  $\leq$  2 %.
- b. Guaranteed by design, not subject to production testing.
- c. Independent of operating temperature.

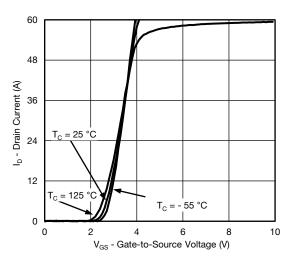
Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.



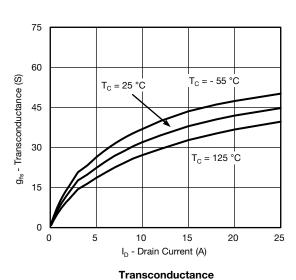
## **TYPICAL CHARACTERISTICS** (T<sub>A</sub> = 25 °C, unless otherwise noted)

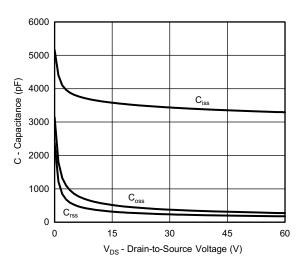


#### **Output Characteristics**

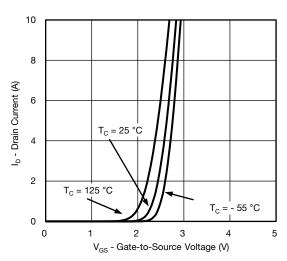


## **Transfer Characteristics**

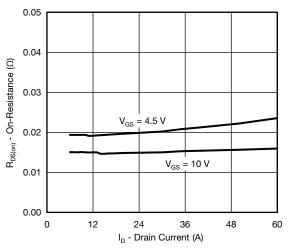




#### Capacitance



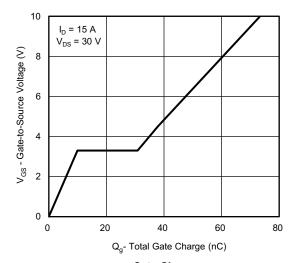
## **Transfer Characteristics**



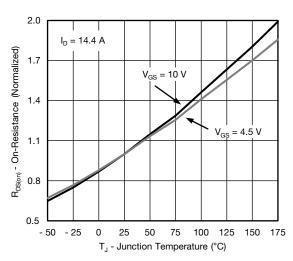
**On-Resistance vs. Drain Current** 



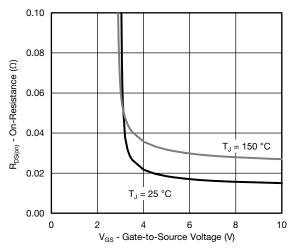
## **TYPICAL CHARACTERISTICS** (T<sub>A</sub> = 25 °C, unless otherwise noted)



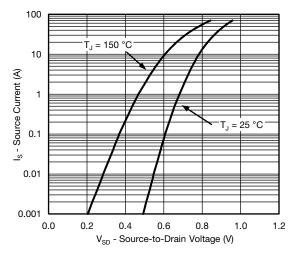
#### **Gate Charge**



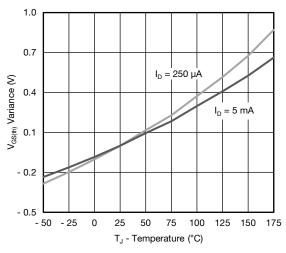
On-Resistance vs. Junction Temperature



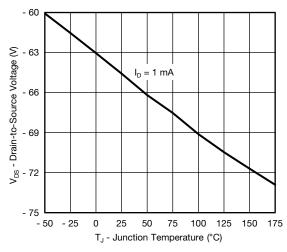
On-Resistance vs. Gate-to-Source Voltage



**Source Drain Diode Forward Voltage** 



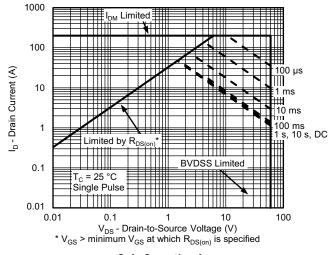
Threshold Voltage



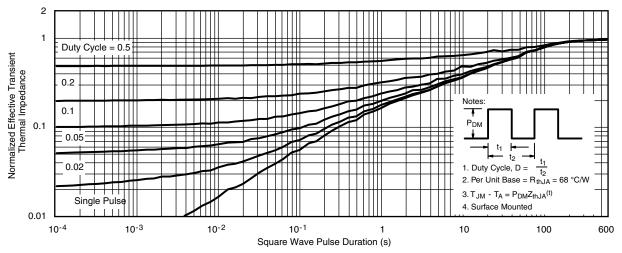
**Drain Source Breakdown vs. Junction Temperature** 



## **THERMAL RATINGS** ( $T_A = 25$ °C, unless otherwise noted)

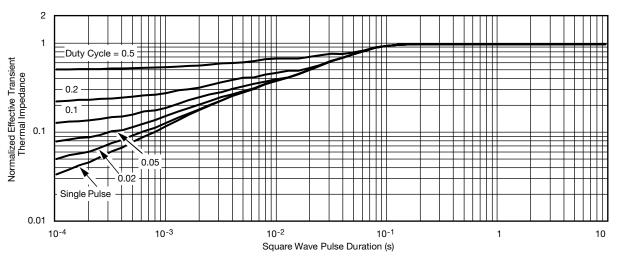


Safe Operating Area



Normalized Thermal Transient Impedance, Junction-to-Ambient

## THERMAL RATINGS (T<sub>A</sub> = 25 °C, unless otherwise noted)



Normalized Thermal Transient Impedance, Junction-to-Case

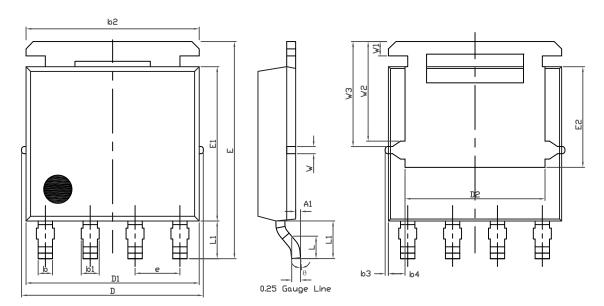
#### Note

- The characteristics shown in the two graphs
  - Normalized Transient Thermal Impedance Junction-to-Ambient (25 °C)
- Normalized Transient Thermal Impedance Junction-to-Case (25 °C) are given for general guidelines only to enable the user to get a "ball park" indication of part capabilities. The data are extracted from single

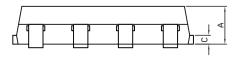
pulse transient thermal impedance characteristics which are developed from empirical measurements. The latter is valid for the part mounted on printed circuit board - FR4, size 1" x 1" x 0.062", double sided with 2 oz. copper, 100 % on both sides. The part capabilities can widely vary depending on actual application parameters and operating conditions.

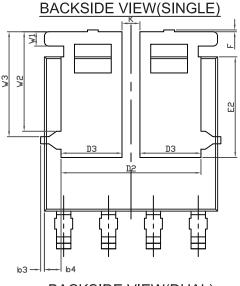
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# PowerPAK® SO-8L Case Outline for Al Parts



**TOPSIDE VIEW** 





BACKSIDE VIEW(DUAL)



DIM.		MILLIMETERS			INCHES		
	MIN.	NOM.	MAX.	MIN.	NOM.	MAX	
Α	1.00	1.07	1.14	0.039	0.042	0.045	
A1	0.00	-	0.127	0.00	-	0.005	
b	0.33	0.41	0.48	0.013	0.016	0.019	
b1	0.44	0.51	0.58	0.017	0.020	0.023	
b2	4.80	4.90	5.00	0.189	0.193	0.197	
b3		0.094			0.004		
b4		0.47			0.019		
С	0.20	0.25	0.30	0.008	0.010	0.012	
D	5.00	5.13	5.25	0.197	0.202	0.207	
D1	4.80	4.90	5.00	0.189	0.193	0.197	
D2	3.86	3.96	4.06	0.152	0.156	0.160	
D3	1.63	1.73	1.83	0.064	0.068	0.072	
е		1.27 BSC		0.050 BSC			
Е	6.05	6.15	6.25	0.238	0.242	0.246	
E1	4.27	4.37	4.47	0.168	0.172	0.176	
E2	2.75	2.85	2.95	0.108	0.112	0.116	
F	-	-	0.15	-	-	0.006	
L	0.62	0.72	0.82	0.024	0.028	0.032	
L1	0.92	1.07	1.22	0.036	0.042	0.048	
K		0.51			0.020		
W		0.23			0.009		
W1		0.41			0.016		
W2	2.82			0.111			
W3		2.96			0.117		
q	0°	-	10°	0°	-	10°	

ECN: C15-1203-Rev. A, 07-Sep-15

DWG: 6044

## Note

· Millimeters will gover



## RECOMMENDED MINIMUM PAD FOR PowerPAK® SO-8L SINGLE



Recommended Minimum Pads Dimensions in mm (inches)



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